NSN 5961-01-331-2897

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-331-2897

View Online at https://aerobasegroup.com/nsn/5961-01-331-2897
Inclosure Material:
Metal
Overall Length:
Between 1.409 inches and 1.573 inches
Overall Height:
Between 0.250 inches and 0.450 inches
Overall Width:
Between 0.990 inches and 1.050 inches
End Application:
Tactical air operations central an/tyq-2 (v) 1
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-3
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Unthreaded hole
Features Provided:
Hermetically sealed case and electrostatic sensitive
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
800.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open
Current Rating Per Characteristic:
1.00 amperes source cutoff current and 0.25 amperes source cutoff current
Power Rating Per Characteristic:
50.0 watts small-signal input power, common-collector preset
Transfer Ratio:
20.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Terminal Type And Quantity:
2 pin and 1 case
Shelf Life:
N/a
Unit Of Measure:

--

NSN 5961-01-331-2897

Transistor - Page 2 of 2



Demilitarization:

No

Fiig:

A110a0